

Fig. 20B-5-001. SbSI–SbSeI. a , b , c vs. x [75Spi]. x : mol% of SbSeI. Orthorhombic cell.

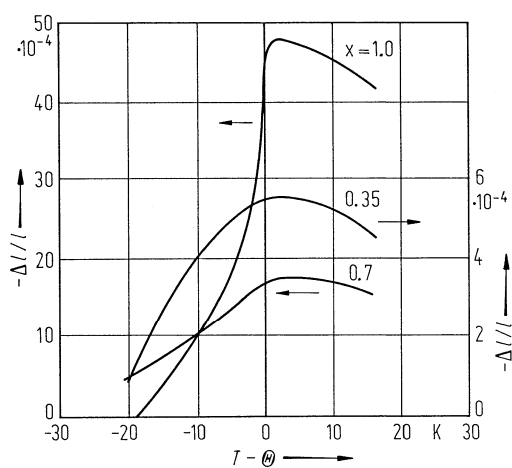


Fig. 20B-5-002. SbSI–SbSeI. $-\Delta l/l$ vs. $(T - \Theta)$ [83Zic]. $\Delta l/l$: linear thermal expansion along c axis. Parameter: x in $\text{Se}_{1-x}\text{S}_x\text{SbI}$.

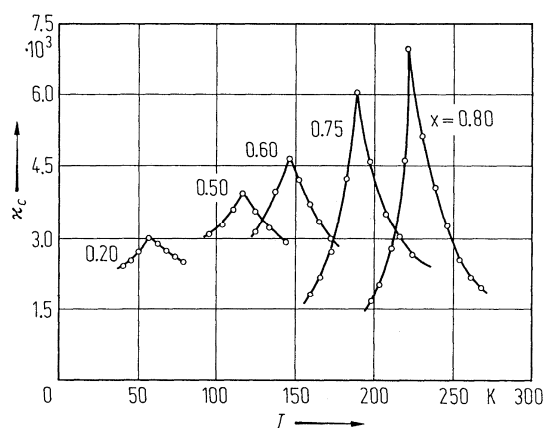


Fig. 20B-5-003. SbSI–SbSeI. κ_c vs. T [73Pou]. Parameter: x , mole fraction of SbSI in $\text{SbS}_x\text{Se}_{1-x}\text{I}$.

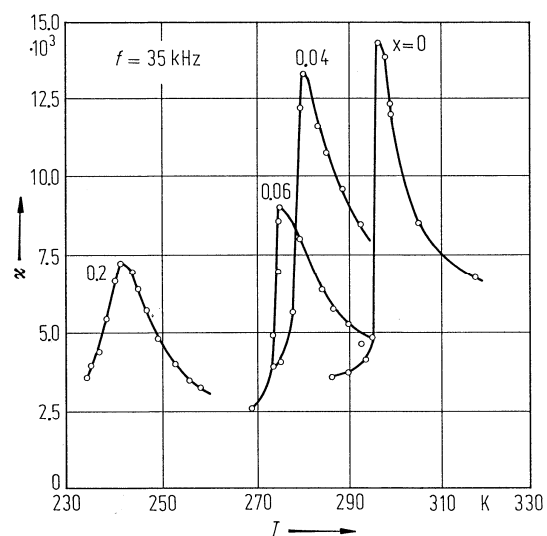


Fig. 20B-5-004. SbSI-SbSeI. κ vs. T [81Ger]. Parameter: x in $\text{Se}_x\text{Sb}_{1-x}\text{SbI}$.

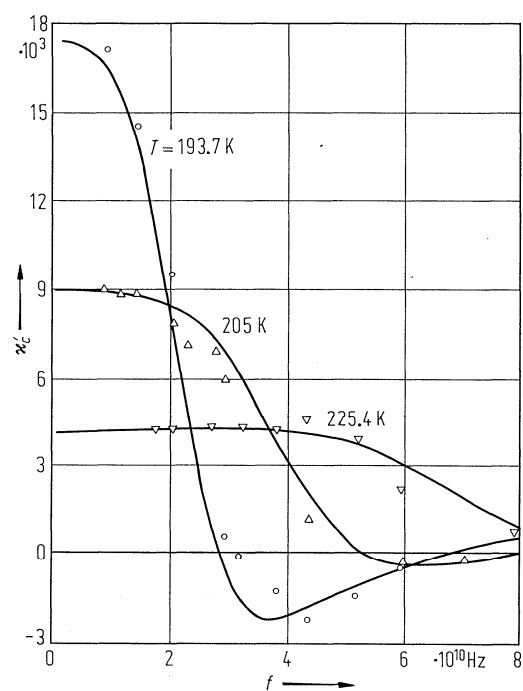


Fig. 20B-5-005. SbSI-SbSeI. κ'_c vs. f [83Kal]. Parameter: T . Molar fraction x of Se in $\text{Se}_x\text{Sb}_{1-x}\text{SbI}$ is 0.3.

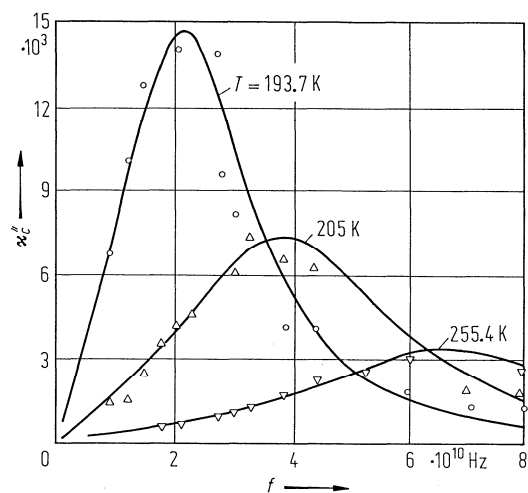


Fig. 20B-5-006. SbSI–SbSeI. κ''_c vs. f [83Ka]. Parameter: T . Molar fraction x of Se in $\text{Se}_x\text{S}_{1-x}\text{SbI}$ is 0.3.

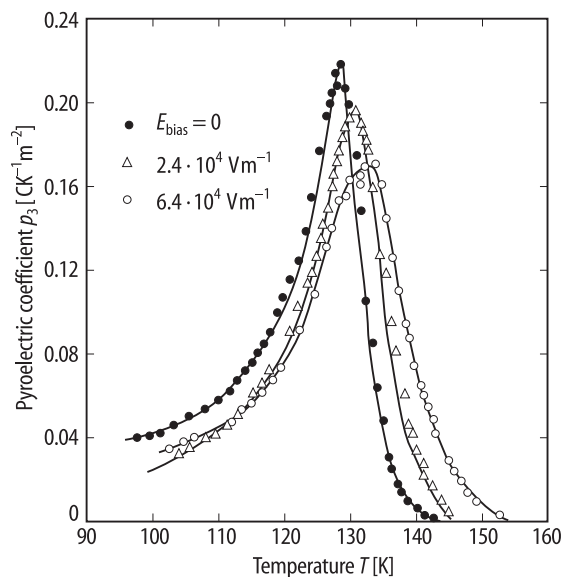


Fig. 20B-5-007. SbSI–SbSeI (crystal). p_3 vs. T [83Cha]. Parameter: E_{bias} . Full circles: $E_{\text{bias}} = 0$, triangles: $E_{\text{bias}} = 2.4 \cdot 10^4 \text{ V m}^{-1}$, open circles: $E_{\text{bias}} = 6 \cdot 10^4 \text{ V m}^{-1}$. Molar fraction x of Se in $\text{Se}_x\text{S}_{1-x}\text{SbI}$ is 0.5.